Analog Power AM70N03-08D

N-Channel 30-V (D-S) MOSFET

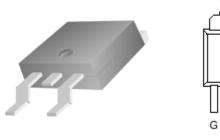
These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

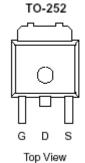
•	Low $r_{DS(on)}$ provides higher efficiency and
	extends battery life

- Low thermal impedance copper leadframe DPAK saves board space
- Fast switching speed
- High performance trench technology

Pb-free
RoHS
COMPLIANT
HALOGEN
FREE

PRODUCT SUMMARY				
V _{DS} (V)	$r_{DS(on)} m(\Omega)$ $I_D(A)$			
30	$8.5 @ V_{GS} = 10V$	63		
	$11.5 @ V_{GS} = 4.5V$	54		





ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Limit	Units	
Drain-Source Voltage		V_{DS}	30	V	
Gate-Source Voltage		V_{GS}	±20	v	
Continuous Drain Current ^a	$T_C=25^{\circ}C$	I_D	63	A	
Pulsed Drain Current ^b		I_{DM}	50	A	
Continuous Source Current (Diode Conduction) ^a		I_S	30	A	
Power Dissipation ^a	$T_C=25^{\circ}C$	P_{D}	50	W	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 175	°C	

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Maximum	Units		
Maximum Junction-to-Ambient ^a	$R_{ heta JA}$	50	°C/W		
Maximum Junction-to-Case	$R_{ heta JC}$	3.0	°C/W		

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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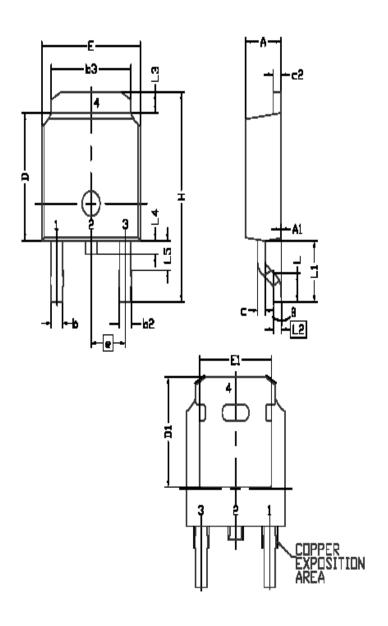
SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)						
Parameter	Cymbal	Test Conditions		Limits		
Farameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static	-		-		•	•
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$	1		3	V
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = 20 \text{ V}$			±100	nA
Zero Gate Voltage Drain Current	$I_{ m DSS}$	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA
On-State Drain Current ^A	$I_{D(on)}$	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$ $V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	34		25	A
Drain-Source On-Resistance ^A	r _{DS(on)}	$V_{GS} = 10 \text{ V}, I_D = 7 \text{ A}$			8.5	mΩ
	¹ DS(on)	$V_{GS} = 4.5 \text{ V}, I_D = 6 \text{ A}$			11.5	11152
Forward Tranconductance ^A	$g_{ m fs}$	$V_{DS} = 15 \text{ V}, I_{D} = 7 \text{ A}$		22		S
Diode Forward Voltage	V_{SD}	$I_S = 7 A, V_{GS} = 0 V$		1.1		V
Dynamic ^b						
Total Gate Charge	Q_{g}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$		16		
Gate-Source Charge	Q_{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_{D} = 7 \text{ A}$		5		nC
Gate-Drain Charge	Q_{gd}			6		
Input Capacitance	C_{iss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V},$		1700		
Output Capacitance	C_{oss}	$v_{DS} = 15 \text{ v}, v_{GS} = 0 \text{ v},$ $f = 1 \text{MHz}$		280		pF
Reverse Transfer Capacitance	C_{rss}	I = IWIHZ		240]
Turn-On Delay Time	$t_{d(on)}$			5		
Rise Time	t _r	$V_{DD} = 25 \text{ V}, R_L = 25 \Omega, I_D = 7 \text{ A},$ $V_{GEN} = 10 \text{ V}$		4		nS
Turn-Off Delay Time	$t_{d(off)}$			23		
Fall-Time	t_{f}			9		

Notes

- a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.
- b. Guaranteed by design, not subject to production testing.

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Package Information



CAMPE	DIMENS:	iinal i	RECINTS	
LOEMY2	MI	ē	MAX	
E	6.40	6.60	6.731	
Г	1.40	1.52	1.77	
L1	a.		ΞF	
L2		508 BS	C	
L3	0.89		1.27	
L4	0.64	I	1.01	
15	1	1	-	
D	6.00	6.10	6,223	
Н	9.40	10,00	10.40	
6	0.64	0.76	0.88	
p5	0.77	0.84	1.14	
b3	5.21	5.34	5.46	
•	2.296 BSC			
A	2.20	2.30	5'38	
A1	0		0.127	
u	0.45	<u>5</u>	0.60	
C2	0.45	0.50	0.58	
и	5.30			
0.	4.40	I	1	
θ	9	ļ	10*	

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